

## Service Manual

# Nakamichi BlackBox Series

PS-100	Power Supply
SF-100	Sub-sonic Filter
LA-100	Line Amplifier
BA-150	Bridging Adaptor
MB-150	MC Booster Amplifier
EC-100	Electronic Crossover
MX-100	Microphone Mixer



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#### 1. PS-100 POWER SUPPLY

#### General

#### **PS-100 Power Supply**

PS-100 is a regulated power supply unit designed to be a power supply for the BlackBox Series (the rated output current: ±200 mA).

Although PS-100 is provided only with one output terminal, two input/output terminals on the other units of the BlackBox Series make multiple connection of PS-100 possible.

To prevent noise signal generation on switching ON/OFF the power supply, PS-100 produces a mute signal, muting output terminals of each unit furnished with a muting circuit

Refer to Table 1 showing how many units of the Black-Box Series can be driven by a single PS-100.

#### **Mute Signal**

Mute signal is muted for a certain period of time to prevent transient noise when power is ON or OFF.

#### Power ON

Transformer output is rectified through diode D403 and smoothed by capacitor C408. Therefore, positive potential appears at C408 (transistor Q411 base). Accordingly, Q411 is in the cutoff state. C409 (22  $\mu$ F) is charged with negative potential through R414 (1 M $\Omega$ ), therefore at the level where the voltage across C409 exceeds Vbe (base-emitter voltage) of Q412, Q412 turns from OFF to ON.

As a result, Q413 turns on and the mute signal is changed from  $\pm$  V to  $\pm$ 10 V, releasing the mute state.

(The mute time depends on C409 and R414 after power is ON.)

#### Power OFF

Transformer output becomes zero and so C408 is charged with negative potential through R415. At the level where the voltage across C408 exceeds Vbe of Q411, Q411 turns from OFF to ON and C409 is quickly discharged. Thus, Q412 is cut off and Q413 is also cut off. Therefore the mute signal becomes + V (i.e. mute state). D402 acts to prevent + V from being discharged easily when power is OFF.

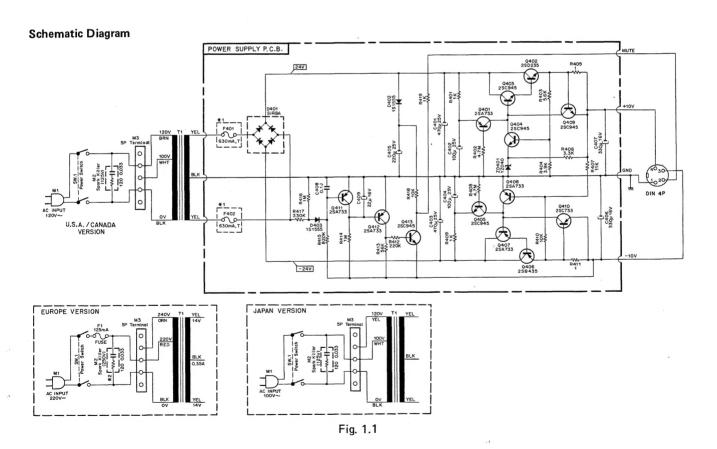
#### **Specifications**

190(W) x 60(H) x 99(D) mm

Weight . . . . . . . . . . . . . . . . . 3.5 lb, 1.6 kg

Table 1	Combinations	of	Units Driven	by	a single PS-100
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Тур	Туре		SF-100 Sub-sonic Filter	LA-100 Line Amplifier	BA-150 Bridging Adaptor	MB-150 MC Booster Amplifier	EC-100 Electronic Crossover	MX-100 Microphone Mixer
Rating		4 VA (±200 mA)	0.5 VA (±25 mA)	0.5 VA (±25 mA)	1 VA (±50 mA)	2 VA (±100 mA)	1 VA (±50 mA)	2 VA (±100 mA)
	1		0	0	0	0		
	2		0	0	0	-		0
	3		0	0			0	0
Combination	4		0	0		0	0	
	5				0	0	0	
	6				0		0	0
	7					0		0
Maximum Drivable Number of Units			8	8	4	2	4	2



- Notes: 1. Fuses marked with \*1 are not incorporated in the U.S.A. version.
  - 2. The type of spark killer marked with \*2 differs in some countries.



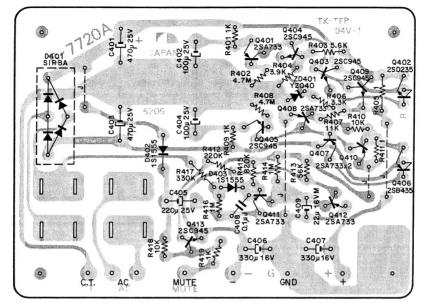


Fig. 1.2

Schematic Ref. No.	Part No.	Descript	ion	Schematic Ref. No.	Part No.	Description
	BA03855A	PS-100 P.C.B. Ass'	1	C405	0B01391A	Electrolytic Capacitor 220µ 25V
	0B07720A	Power Supply P.C.I	3.	C406,407	0B01502A	Electrolytic Capacitor
Q401,407	0B06013A	Transistor	2SA733			330µ 16V
408,410				C408	0B01780A	Mylar Capacitor 0.1μ 50V J
411,412				C409	0B05820A	Electrolytic Capacitor
Q402	0B01823A	Transistor	2SD235 (Y)			22μ 16V M
Q403,404	0B01872A	Transistor	2SC945			(MS)
405,409					0J03597B	Heat Sink (1 pce.)
413					0E00607A	Screw M3x8 Philips Pan Head
Q406	0B06011A	Transistor	2SB435			(3A) (4 pcs.)
D401	0B06088A	Silicon Diode	S1RBA		0E00507A	Nut Hex. M3 (2 pcs.)
D402,403	0B01909A	Silicon Diode	1S1555			
ZD401	0B06063A	Zener Diode	YZ040B			
R401,409	0B01781A	Carbon Resistor	1K ERD-25V J			
419						
R402,408	0B05824A	Carbon Resistor	4.7M ERD-50T J			
R403	0B05673A	Carbon Resistor	5.6K ERD-25V J			
R404	0B05664A	Carbon Resistor	3.9K ERD-25V J			
R405,411	0B05746A	Carbon Resistor	1 ERD-25V J			
R406	0B01793A	Carbon Resistor	3.3K ERD-25V J			
R407	0B05826A	Carbon Resistor	11K ERD-25V J			
R410,418	0B01833A	Carbon Resistor	10K ERD-25V J			
R412	0B05596A	Carbon Resistor	220K ERD-25V J			
R413	0B05563A	Carbon Resistor	56K ERD-25V J			
R414,416	0B05564A	Carbon Resistor	1M ERD-25V J			
R415	0B05674A	Carbon Resistor	820K ERD-25V J			
R417	0B01921A	Carbon Resistor	330K ERD-25V J			
C401,403	0B01401A	Electrolytic Capaci				
		F	470μ 25V			
C402,404	0B01272A	Electrolytic Capaci				
			100μ 25V			•

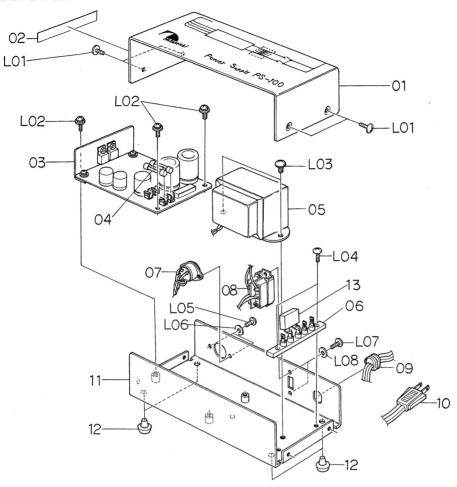


Fig. 1.3

Schematic Ref. No.	Part No.	Description	Q'ty	Schematic Ref. No.	Part No.	Description	Q'ty
		PS-100 Mechanism		11	HA03697C	Main Chassis PS Ass'y	1
				12	0H03437A	Rubber Foot	4
01	0H03509A	Upper Cover PS	1	13	0B08361A	Spark Killer 125 V (R + C)	1
02	OM03799A	Caution Label G	1		0B08363A	Spark Killer 125 V (R + C)	1
	OM03800A	Caution Label H	1		0B08342A	Spark Killer 125 V (R + C)	1
03	BA03855A	PS-100 P.C.B. Ass'y	1		0B08240A	Spark Killer 250 V (R + C)	1
04	0B08161U	Fuse 630 mA	2		0B07096U	Spark Killer (C)	1
05	0B06567A	Power Transformer 100-120 V	1	L01	0E00713A	Screw M3x6 Philips Truss Head	4
	0B06568A	Power Transformer 220–240 V	1	L02	0E00606A	Screw M3x6 Philips Pan Head	3
06	0B08025U	5P Terminal	1			(3A)	
07	0B08355A	4P DIN Socket	1	L03	0E00538A	Screw M4x5 Philips Binding	2
80	0B07172A	Power Switch	1			Head	
	0B07092A	Power Switch	1	L04	0E00594A	Screw M3x8 Philips Binding	2
09	0B08037A	Cord Bushing	1			Head	
	0B08351A	Cord Bushing	1	L05	0E00714A	Screw M2.6x6 Philips Binding	2
	0B08325A	Cord Bushing	1			Head	
10	0B08350A	Power Cord	1	L06	0E00651A	Washer 2.6 mm (plastics)	2
	0B08219B	Power Cord	1	L07	0E00593A	Screw M3x6 Philips Binding	2
	0B08348A	Power Cord	1			Head	
	0B08149U	Power Cord	1	L08	0E00157A	Washer 3 mm (plastics)	2

Notes: 1. 02, 08, 09 and 10 differ in versions.

2. 04 (fuse) is not incorporated in the U.S.A. version.



#### 2 SF-100 SUB-SONIC FILTER

#### General

In disc record reproduction, low-frequency resonance of a tone arm and rumbling of a turn table exist at about 10 Hz and their peak level ranges approximately from 5 to 15 dB

SF-100 is an active filter to eliminate these noises.

The unit is designed so that no low frequency sound recorded on disc records is sacrificed and no change in tones is effected.

To compensate the personal feeling of insufficiency in low frequency sound caused by the insertion of the Sub-sonic Filter, a Low Boost Switch is provided which can boost signal approximately by 5 dB at 30 Hz.

With both of the Filter Switch and Low Boost Switch turned OFF, the input signal directly appears on the output terminals without passing through the Sub-sonic Filter.

The output of the twin-T filter is amplified by Amplifier 2, while the output of the amplifier is positively fed back through  $C_2$  and  $R_2$  to compensate the level reduction in the range of  $20-50\ Hz$ .

Further, to increase the attenuation below 5 Hz, the filter load impedance is lowered with  $R_4$ , and the improvement of characteristics can be realized by changing impedance of every device.

In addition, a high pass filter is incorporated in the input side of Amplifier 1 to ensure an ideal sub-sonic filtering characteristics.

#### **Specifications**

Maximum Power Consumption . . . 0.5 VA Current Consumption . . . . . . 25 mA

Total Harmonic Distortion . . . . . less than 0.005% (50 Hz -

20 kHz, 1 V Output)

Frequency Response . . . . . . . . . 40 Hz - 100 kHz ± 0.5 dB

Sub-sonic Filter . . . . . . . . . . . . 10 Hz: -50 dB,

-40 dB (with Low

Boost)

Low Boost . . . . . . . . . . . . . . . . 30 Hz: + 5 dB

Signal-to-Noise Ratio . . . . . . better than 110 dB (IHF-A

Network)

Mute Function . . . . . . . . . Furnished

Dimensions . . . . . . . . . . . . . . . . . 7-1/2(W)  $\times$  2-3/8(H)  $\times$ 

4-1/16(D) inches

190(W) x 60(H) x 103(D) mm

Weight . . . . . . . . . . . . . . 2.7 lb, 1.2 kg

#### System Diagram

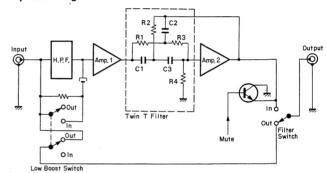


Fig. 2.1

Schematic Ref. No.	Part No.	Descript	ion	Schematic Ref. No.	Part No.	Descr	ription	
	BA03849A	SF-100 P.C.B. Ass	у	R114,115	0B05562A	Carbon Resistor	47K	ERD-25V J
				119,214				
	0B07719A	SF P.C.B.		215,219				
Q101,102	0B06062A	Transistor	2SC1222 (2)	R116,216	0B05678A	Carbon Resistor	560	ERD-25V J
201,202				R117,118	0B05567A	Carbon Resistor	33	ERD-25V J
Q103,104	0B06013A	Transistor	2SA733	217,218				
203,204				C101,201	0B05682A	Mylar Capacitor	$0.068\mu$	50V J
Q105,205	0B01872A	Transistor	2SC945 (L)	C102,202	0B01863A	Electrolytic Capa		
D101,102	0B01909A	Silicon Diode	1S1555				$3.3\mu$	16V
103,201				C103,105	0B05844A	Mylar Capacitor	$0.33\mu$	50V J
202,203				203,205				
R101,201	0B05700A	Carbon Resistor	470K ERD-25V J	C104,204	0B05832A	Mylar Capacitor	$0.018\mu$	50V J
R102,202	0B05564A	Carbon Resistor	1M ERD-25V J	C106,206	0B05639A	Electrolytic Capa		
R103,203	0B05563A	Carbon Resistor	56K ERD-25V J				$1.5\mu$	35V M
R104,204	0B05608A	Carbon Resistor	220 ERD-25V J		ì			(MS)
R105,205	0B01789A	Carbon Resistor	330 ERD-25V J	C107,108	0B05884A	Electrolytic Capa		
R106,206	0B05664A	Carbon Resistor	3.9K ERD-25V J	207,208			$470\mu$	10V
R107,207	0B01564A	Carbon Resistor	82K ERD-25V J		0B07167A	Push Switch	(1 pce	e.)
R108,109	0B01921A	Carbon Resistor	330K ERD-25V J	CN1	0B08182A	6P-T Post		
208,209				CN2	0B08236A	4P-T Post		
R110,210	0B01795A	Carbon Resistor	4.7K ERD-25V J					
R111,211	0B01902A	Carbon Resistor	68K ERD-25V J					
R112,212	0B05569A	Carbon Resistor	47 ERD-25V J			-		
R113,213	0B05565A	Carbon Resistor	1.2K ERD-25V J			-		

#### Schematic Diagram

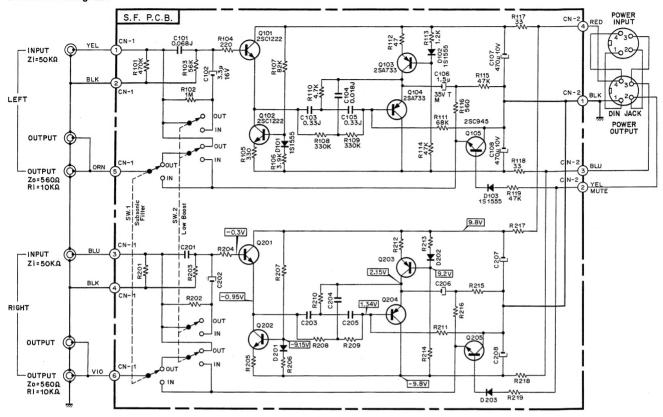


Fig. 2.2

#### Mounting Diagram and Parts List

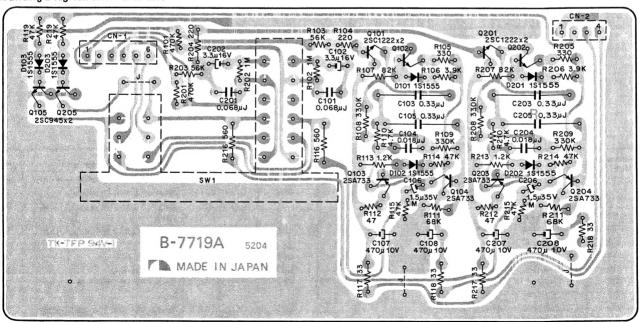


Fig. 2.3



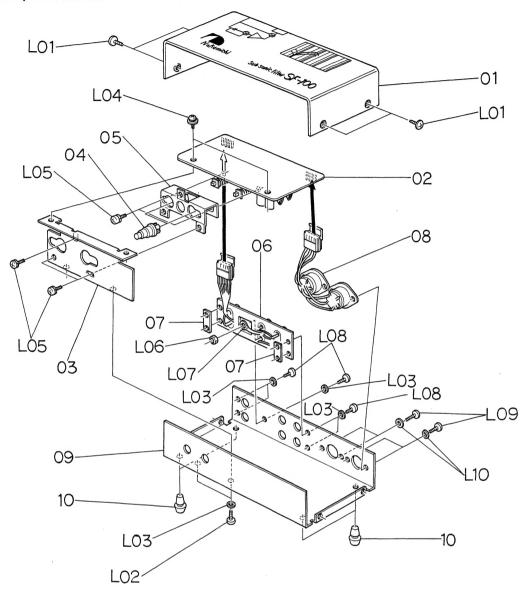


Fig. 2.4

Schematic Ref. No.	Part No.	Description	Q'ty	Schematic Ref. No.	Part No.	Description	Q'ty
		SF-100 Mechanism		L03	0E00157A	Washer 3 mm (plastics)	7
				L04	0E00606A	Screw M3x6 Philips Pan Head	2
01	0H03507A	Upper Cover SF	1			(3A)	
02	BA03849A	SF-100 P.C.B. Ass'y	1	L05	0E00612A	Screw M3x6 Philips Pan Head	5
03	0J03654B	Front Chassis	1			(2A)	
04	JA03061A	Push Button Ass'y	2	L06	0E00507A	Nut Hex. M3	1
05	0J03440A	Switch E Block Base	1	L07	0E00037A	Earth Lug B-5	1
06	0B08290B	6P Pin Jack	1	L08	0E00594A	Screw M3x8 Philips Binding	5
07	0J03277A	Metal Seat Nut	2			Head	
80	0B08355A	4P DIN Socket	2	L09	0E00714A	Screw M2.6x6 Philips Binding	4
09	0H03508B	Main Chassis SF	1			Head	
10	0H03437A	Rubber Foot	4	L10	0E00651A	Washer 2.6 mm (plastics)	4
L01	0E00713A	Screw M3x6 Philips Truss Head	4	1			
L02	0E00593A	Screw M3x6 Philips Binding	2				
		Head					



#### 3. LA-100 LINE AMPLIFIER

#### General

LA-100 is an amplifier with a flat frequency response that may be inserted between amplifiers connected to input or output of a tape deck or the like when the gain of the amplifiers is insufficient.

The gain is selectable at four levels, 0, +6, +12, and +18 dB by combination of IN/OUT of two gain switches of 6 dB and 12 dB.

The voltage amplification of LA-100 at each status of the switches is as follows:

S<sub>1</sub>: open, S<sub>2</sub>: close;  

$$A_{v(1)} = \frac{9.1 \text{ k} // 27 \text{ k}}{6.8 \text{ k}} = 1 \text{ [0 dB]}$$

S<sub>1</sub>: close, S<sub>2</sub>: close;  

$$A_{U(2)} = \frac{9.1 \text{ k} // 27 \text{ k}}{6.8 \text{ k} // 6.8 \text{ k}} = 2 \quad [6 \text{ dB}]$$

S<sub>1</sub>: open, S<sub>2</sub>: open;  

$$A_{U(3)} = \frac{(1M + 9.1 \text{ k}) // 27 \text{ k}}{6.8 \text{ k}} \stackrel{.}{=} 4 \quad [12 \text{ dB}]$$

$$S_1$$
: close,  $S_2$ : open;  

$$A_{\mathcal{U}(4)} = \frac{(1M + 9.1 \text{ k}) // 27 \text{ k}}{6.8 \text{ k} // 6.8 \text{ k}} \stackrel{.}{=} 8 \quad [18 \text{ dB}]$$

#### **Specifications**

Maximum Power Consumption . . . 1 VA Current Consumption . . . . . . 50 mA

Total Harmonic Distortion . . . . . 0.005% (20 Hz - 20 kHz,

1 V Output)

Frequency Response . . . . . . . . . 10 Hz - 75 kHz + 0,

-0.5 dB

Signal-to-Noise Ratio ..... better than 100 dB (+ 18 dB

Gain)

Reference Level . . . . . . . . . Gain Switch 0 dB: 1V

6 dB: 0.5 V 12 dB: 0.25 V

18 dB: 0.126 V

4-1/16(D) inches

 $190(W) \times 60(H) \times 103(D) mm$ 

Weight . . . . . . . . . . . . . . . 2.7 lb, 1.2 kg

#### System Diagram

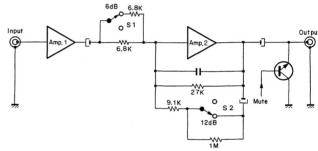


Fig. 3.1

#### **Schematic Diagram**

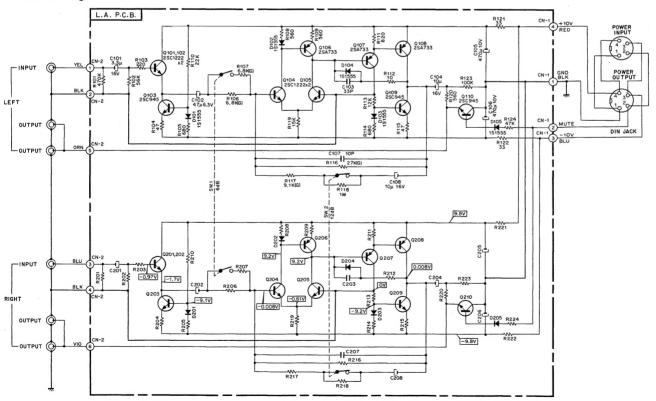


Fig. 3.2



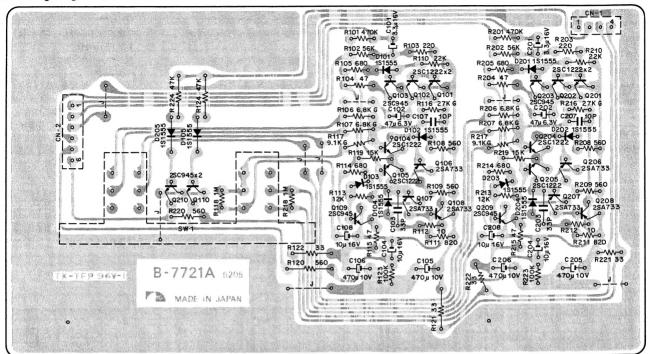


Fig. 3.3

Schematic Ref. No.	Part No.	Description	on		Schematic Ref. No.	Part No.	Descript	ion	
	BA03859A	LA-100 P.C.B. Ass'y	,		R110,210	0B05661A	Carbon Resistor	22K	ERD-14V J
					R111,211	0B05511A	Carbon Resistor	820	ERD-14V J
	0B07721A	LA P.C.B.			R112,212	0B05663A	Carbon Resistor	10	ERD-14V J
Q101,102	0B06062A	Transistor	2SC12	222 (2)	R113,213	0B05650A	Carbon Resistor	12K	ERD-14V J
104,105					R116,216	0B05935A	Metal Film Resistor	27K	ER0-25VK
201,202									G
204,205					R117,217	0B05934A	Metal Film Resistor	9.1K	ER0-25VK
Q103,109	0B01872A	Transistor	2SC94	15					G
110,203					R118,218	0B05564A	Carbon Resistor	1M	ERD-14V J
209,210					R119,219	0B05591A	Carbon Resistor	15K	ERD-14V J
Q106,107	0B06013A	Transistor	2SA73	33	R121,122	0B05567A	Carbon Resistor	33	ERD-14V J
108,206		7			221,222				
207,208					R123,223	0B01920A	Carbon Resistor	100K	ERD-14V J
D101,102	0B01909A	Silicon Diode	18155	5	R124,224	0B05562A	Carbon Resistor	47K	ERD-14V J
103,104					C101,201	0B01863A	Electrolytic Capacit	or	
105,201								$3.3\mu$	16V
202,203					C102,202	0B01404A	Electrolytic Capacit	or	
204,205								$47\mu$	6.3V
R101,201	0B05700A	Carbon Resistor	470K	ERD-14V J	C103,203	0B05744A	Ceramic Capacitor	33P	
R102,202	0B05563A	Carbon Resistor	56K	ERD-14V J	C104,108	0B01412A	Electrolytic Capacit	or	
R103,203	0B05608A	Carbon Resistor	220	ERD-14V J	204,208			10μ	16V
R104,115	0B05569A	Carbon Resistor	47	ERD-14V J	C105,106	0B05884A	Electrolytic Capacit	or	
204,215					205,206			470μ	10V
R105,114	0B05559A	Carbon Resistor	680	ERD-14V J	C107,207	0B05798A	Ceramic Capacitor	10P	
205,214					SW1	0B07170A	Push Switch	SUE2	2
R106,107	0B05933A	Metal Film Resistor	6.8K	ER0-25VK	CN1	0B08236A	4P-T Post		
206,207				G	CN2	0B08182A	6P-T Post		
R108,109	0B05678A	Carbon Resistor	560	ERD-14V J					
120,208									
209,220									



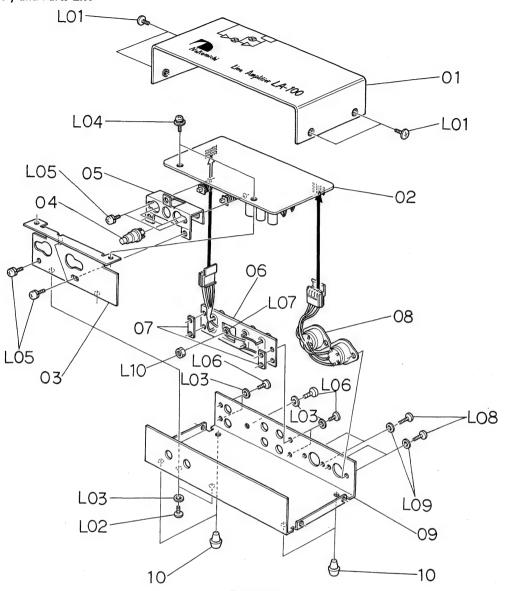


Fig. 3.4

Schematic Ref. No. Part No.		Description	Q'ty	Schematic Ref. No.	Part No.	Description	Q'ty
		LA-100 Mechanism		L03	0E00157A	Washer 3 mm (plastics)	7
				L04	0E00606A	Screw M3x6 Philips Pan Head	2
01	0H03518A	Upper Cover LA	1			(3A)	
02	BA03859A	LA-100 P.C.B. Ass'y	1	L05	0E00612A	Screw M3x6 Philips Pan Head	5
03	0J03654B	Front Chassis	1			(2A)	
04	JA03061A	Push Button Ass'y	2	L06	0E00594A	Screw M3x8 Philips Binding	5
05	0J03440A	Switch E Block Base	1			Head	
06	0B08290B	6P Pin Jack	1	L07	0E00037A	Earth Lug B-5	1
07	0J03277A	Metal Seat Nut	2	L08	0E00714A	Screw M2.6x6 Philips Binding	4
80	0B08355A	4P DIN Socket	2			Head	
09	0H03519A	Main Chassis LA	1	L09	0E00651A	Washer 2.6 mm (plastics)	4
10	0H03437A	Rubber Foot	4	L10	0E00507A	Nut Hex. M3	1
L01	0E00713A	Screw M3x6 Philips Truss Head	4				
L02	0E00593A	Screw M3x6 Philips Binding	2				
		Head					



#### 4. BA-150 BRIDGING ADAPTOR

#### General

Except for the exclusion of power supply from BA-150, BA-150 is identical to the BA-100 presently available. Connection of BA-150 across a preamplifier and stereo power amplifiers allows the usage of stereo power amplifiers in monaural use, and delivers the power amplifier output twice the output in the stereophonic configuration. The use of Nakamichi 420 or 620 power amplifier permits the power output increase to 120W or 350W, respectively, and thus the sound quality is expected to be improved.

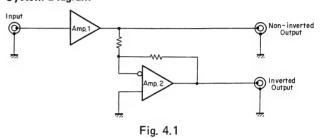
Transistors Q101 and Q102 in the first stage constitute an emitter follower and a constant current power supply respectively. Q104 and Q105 constitute a differential amplifier, and Q103 and D101 provide a current mirror circuit. Q106 and Q107 constitute a phase inverter and the output of Q107 is a phase-inverted signal of the input; that is, this unit, receives an input signal and outputs it as a non-inverted output and a phase-inverted output, and permits bridging of the left and right outputs of the power amplifiers to form a monaural power amplifier.

#### **Specifications**

3-13/16(D) inches  $190(W) \times 60(H) \times 97(D)$  mm

Weight . . . . . . . . . . . . . . 2.4 lb, 1.1 kg

#### System Diagram



#### Schematic Diagram

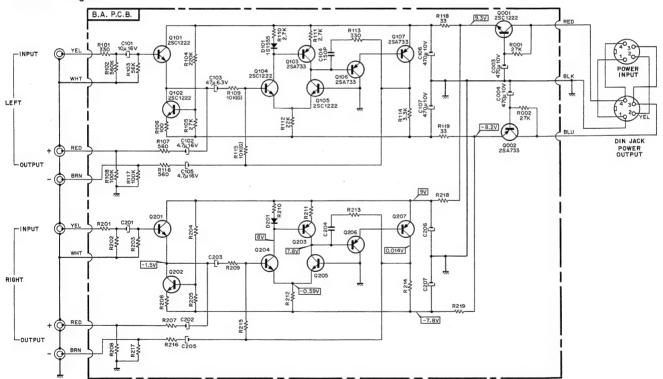


Fig. 4.2

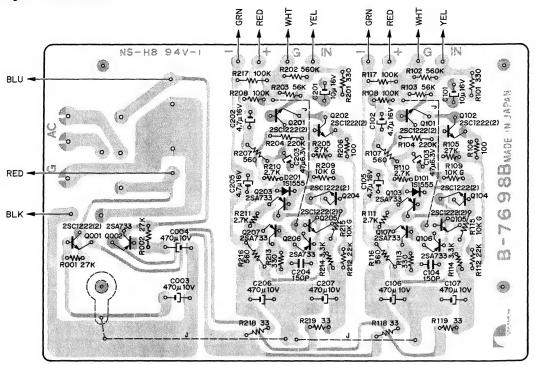


Fig. 4.3

Schematic Ref. No.	Part No.	Descripti	on	Schematic Ref. No.	Part No.	Descript	tion	
	BA03863A	BA-150 P.C.B. Ass'	у	R118,119 218,219	0B05567A	Carbon Resistor	33	ERD-14V J
	0B07698B	BA P.C.B.		C003,004	0B05884A	Electrolytic Capacito	or	
Q001,101	0B06062A	Transistor	2SC1222 (2)	106,107			470μ	10V
102,104				206,207				
105,201			·	C101,201	0B01412A	Electrolytic Capacito	or	
202,204							$10\mu$	16V
205				C102,105	0B01389A	Electrolytic Capacito	or	
Q002,103	0B06013A	Transistor	2SA733	202,205			$4.7\mu$	16V
106,107				C103,203	0B01404A	Electrolytic Capacito	or .	
203,206							$47\mu$	6.3V
207				C104,204	0B05599A	Ceramic Capacitor	150P	50V
D101,201	0B01909A	Silicon Diode	1S1555	,	0E00037A		(1 pce	.)
R001,002	0B05538A	Carbon Resistor	27K ERD-14V J	1				
105,205				1				
R101,113	0B01789A	Carbon Resistor	330 ERD-14V J					
201,213								
R102,202	0B05665A	Carbon Resistor	560K ERD-14V J					
R103,203	0B05563A	Carbon Resistor	56K ERD-14V J					
R104,204	0B05596A	Carbon Resistor	220K ERD-14V J					
R106,206	0B05558A	Carbon Resistor	100 ERD-14V J					
R107,116	0B05678A	Carbon Resistor	560 ERD-14V J					
207,216								
R108,117	0B01920A	Carbon Resistor	100K ERD-14V J			,		
208,217								
R109,115	0B05895A	Metal Film Resistor	10K ER0-25VK	ľ				
209,215			G					
R110,111	0B01782A	Carbon Resistor	2.7K ERD-14V J					
210,211								
R112,212	0B05661A	Carbon Resistor	22K ERD-14V J					
R114,214	0B01793A	Carbon Resistor	3.3K ERD-14V J					



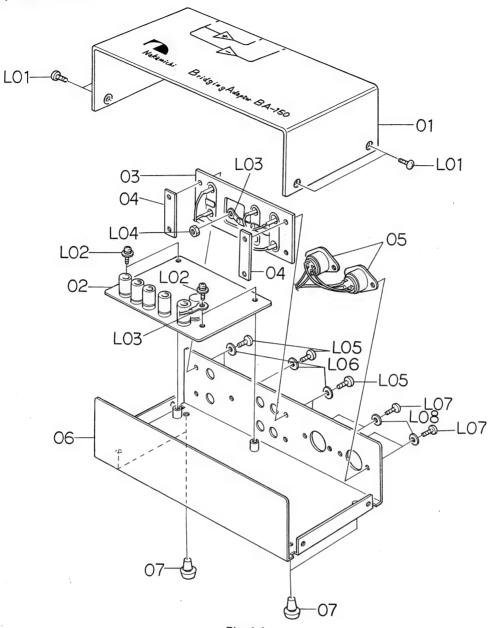


Fig. 4.4

Schematic Ref. No.	Part No.	Description	Q'ty	Schematic Ref. No.	Part No.	Description	Q'ty
		BA-150 Mechanism		L03	0E00037A	Earth Lug B-5	2
				L04	0E00507A	Nut Hex. M3	1
01	0H03523A	Upper Cover BA-150	1	L05	0E00594A	Screw M3x8 Philips Binding	5
02	BA03863A	BA-150 P.C.B. Ass'y	1			Head	
03	0B08290B	6P Pin Jack	1	L06	0E00157A	Washer 3 mm (plastics)	5
04	0J03277A	Metal Seat Nut	2	L07	0E00714A	Screw M2.6x6 Philips Binding	4
05	0B08355A	4P DIN Socket	2			Head	
06	HA03709A	Main Chassis BA Ass'y	1	L08	0E00651A	Washer 2.6 mm (plastics)	4
07	0H03437A	Rubber Foot	4				
L01	0E00713A	Screw M3x6 Philips Truss Head	4		•		
L02	0E00606A	Screw M3x6 Philips Pan Head	4				
		(3A)					



#### 5. MB-150 MC BOOSTER AMPLIFIER

#### General

MB-150 is a booster amplifier used to increase gain for an MC type cartridge at low output level.

The gain can be selected at two levels of 38 dB/22 dB by switching the Gain Switch ON/OFF. With the Pass Switch set to ON, the input from the cartridge is directly delivered as the output without passing through the amplifier.

Complementary circuits used in all stages of MB-150 reduce distortion.

The first stage is composed of 10 PNP transistors and 10 NPN transistors, with low noise figures at small signal source impedance, which are connected in parallel respectively to ensure low noise figures.

The second stage adopts the particular triple transistor configuration as used in the first stage of Nakamichi 610, 410, and 630 Equalizing Amplifiers, and its equivalent input noise figure is less than -158 dB (with RIAA IHF-A Network).

The first-stage transistors have the combination of NPN and PNP. Theoretically, if the characteristics of both types are the same, the collector currents of these transistors are equal, and their base currents are the same if the current amplification  $h_{\rm FE}$ 's are equal; therefore d.c. voltage across the input terminals vanishes at the identical values of + and — power supply voltage. In actual circuits, However, a + or — voltage slightly remains due to various factors and the voltage should be adjusted to zero by offset voltage adjustment.

#### Offset Voltage Adjustment

- 1. Insert shorted pin plugs into input jacks of MB-150.
- 2. Connect a PS-100 power supply unit to the MB-150 and turn the power switch of the PS-100 ON.
- 3. Connect an amplifier to the output jacks and listen to sound with headphones or a speaker.
- Adjust semi-fixed volumes VR101 and VR201 so that switching noises generated at the ON/OFF operation of the pass switch reduce to a inaudible level.

#### **Specifications**

Maximum Power Consumption . . . 2 VA Current Consumption . . . . . . 100 mA

Total Harmonic Distortion . . . . 0.005% (20 Hz - 20 kHz,

0.3 V Output)

Frequency Response . . . . . . . . 20 Hz - 100 kHz + 0, -1 dB

(+ 38 dB Gain) 10 Hz — 100 kHz + 0,

-0.5 dB (+ 22 dB Gain) Equivalent Input Noise . . . . . . -158 dB (RIAA, IHF-A

Network)

Ref. Output Level/Output

Impedance . . . . . . . . . . . . . . . 5 mV/5.6  $\Omega$ 

Ref. Input Level/Input Impedance . 0.4 mV/56  $\Omega$  (+ 22 dB Gain) 63  $\mu$ V/56  $\Omega$  (+ 38 dB Gain)

Maximum Input Level . . . . . . . 200 mV (+ 22 dB Gain)

30 mV (+ 38 dB Gain)

190(W) × 60(H) × 100(D) mm

Weight . . . . . . . . . . . . . . . 2.9 lb, 1.3 kg

#### System Diagram

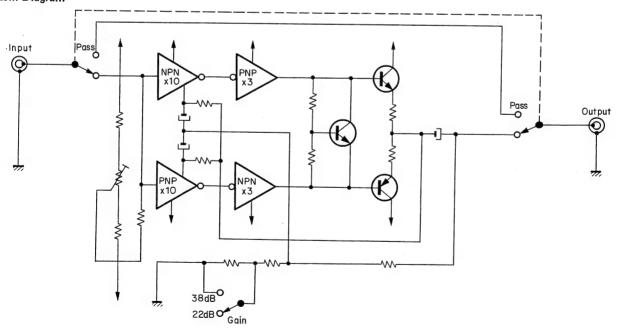


Fig. 5.1



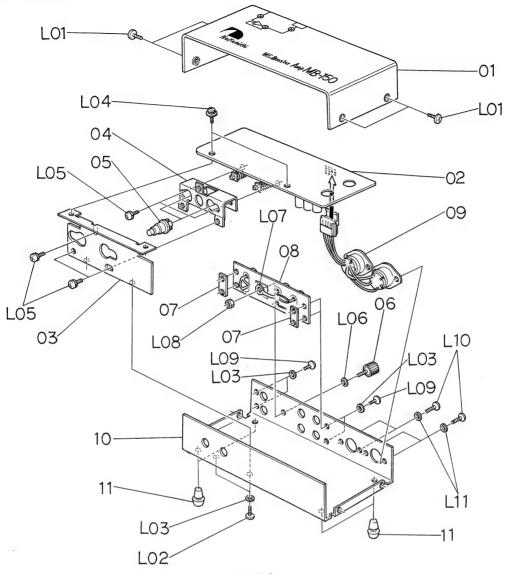


Fig. 5.2

Schematic Ref. No.	Part No.	Description	Q'ty	Schematic Ref. No.	Part No.	Description	Q'ty
		MB-150 Mechanism		L02	0E00593A	Screw M3x6 Philips Binding Head	2
.01	0H03521A	Upper Cover MB	1	L03	0E00157A	Washer 3 mm (plastics)	6
02	BA03860A	MB-150 P.C.B. Ass'y	1	L04	0E00606A	Screw M3x6 Philips Pan Head	2
03	0J03654B	Front Chassis	1			(3A)	
04	0J03440A	Switch E Block Base	1	L05	0E00612A	Screw M3x6 Philips Pan Head	5
05	JA03061A	Push Button Ass'y	2			(2A)	
06	0B03920B	Ground Terminal	1	L06	0E00732A	Washer 3 mm	1
07	0J03277A	Metal Seat Nut	2	L07	0E00037A	Earth Lug B-5	1
80	0B08394A	6P Pin Jack	1	L08	0E00507A	Nut Hex. M3	1
09	0B08355A	4P DIN Socket	2	L09	0E00594A	Screw M3x8 Philips Binding	4
10	0H03522C	Main Chassis MB	1			Head	
11	0H03437A	Rubber Foot	4	L10	0E00714A	Screw M2.6x6 Philips Binding	4
L01	0E00713A	Screw M3x6 Philips Truss	4			Head	
		Head		L11	0E00651A	Washer 2.6 mm (plastics)	4

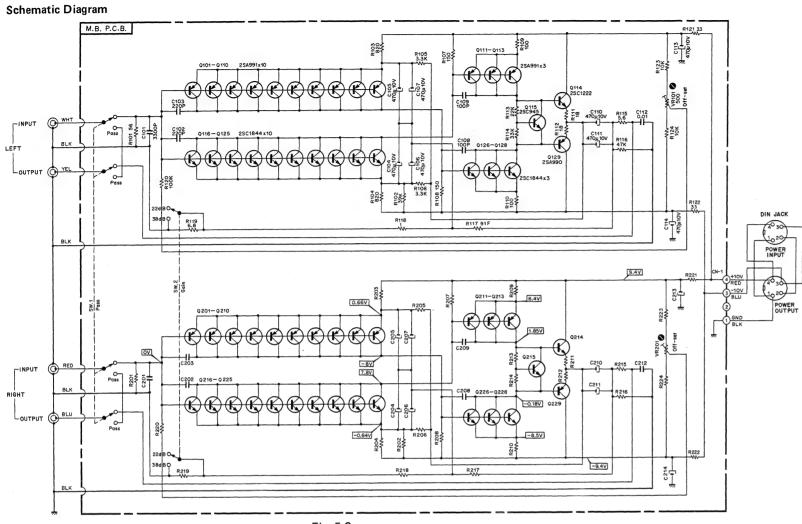
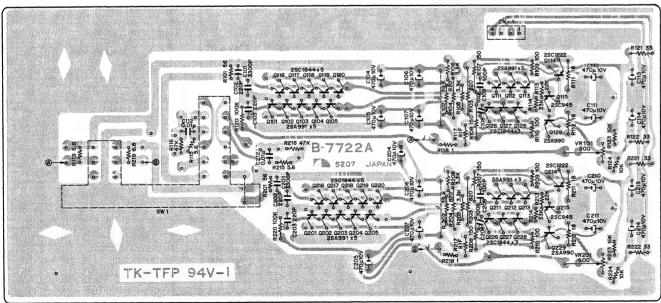


Fig. 5.3



0121 0122 0123 0124 0125 0221 0222 0223 0224 0225

Fig 5.5

(TR P.C.B.)

Fig. 5.4

	<u> </u>	
Schematic Ref. No.	Part No.	Description
	BA03860A	MB-150 P.C.B. Ass'y
	0B07722A	MB P.C.B.
Q101-113 201-213	0B06120A	Transistor 2SA991 (26 pcs.)
Q114,214	0B06062A	Transistor 2SC1222 (2)
Q115,215	0B01872A	Transistor 2SC945
Q116-128 216-228	0B06119A	Transistor 2SC1844 (26pcs.)
Q129,229	0B06121A	Transistor 2SA990
VR101,201	0B07159A	Semi-fixed Volume 500
R101,201	0B05587A	Carbon Resistor 56 ERD-25V J
R102,202	0B01885A	Carbon Resistor 39K ERD-25V J
R103,104	0B05511A	Carbon Resistor 820 ERD-25V J
203,204 R105,106	0B01793A	Carbon Resistor 3.3K ERD-25V J
205,206 R107,108	0B05649A	Carbon Resistor 150 ERD-25V J
207,208 P100,110	0B05558A	Carbon Resistor 100 ERD-25V J
R109,110 209,210		
R111,112 211,212	0B05545A	Carbon Resistor 18 ERD-25V J
R113,213	0B05661A	Carbon Resistor 22K ERD-25V J
R114,214	0B01879A	Carbon Resistor 33K ERD-25V J
R115,215	0B05818A	Carbon Resistor 5.6 ERD-25V J
R116,216	0B05562A	Carbon Resistor 47K ERD-25V J
R117,217	0B05952A	Metal Film Resistor 91 ER0-25VK
R118,218	0B05746A	Carbon Resistor 1 ERD-25V J
R119,219	0B05854A	Carbon Resistor 6.8 ERD-25V J
R120,220	0B01920A	Carbon Resistor 100K ERD-25V J
R121,122	0B05567A	Carbon Resistor 33 ERD-25V J
221,222 R123,124 223,224	0B01833A	Carbon Resistor 10K ERD-25V J
C101,201	0B01914A	Mylar Capacitor 3300P 50V
C102,103	0B01289A	Ceramic Capacitor 220P 50V
202,203 C104,105	0B05884A	Electrolytic Capacitor
106,107	000004A	470μ 10V
113,114 204,205	,	
206,207		
213,214 C108,109	0B01288A	Ceramic Capacitor
208,209		100P 50V
C112,212	0B01290A	Ceramic Capacitor 0.01µ 50V
SW1	0B07167A	Push Switch SVE
CN1	0B08236A	4P-T Post
	0B08366A	Shield Case MB (2 pcs.)
	0B07738A	TR P.C.B. (2 pcs.)
		1



#### 6. EC-100 ELECTRONIC CROSSOVER

EC-100, a combination of a high-pass filter, a phase shifter and an adder, separates an input signal into a high-passed output and a low-passed output.

Each of the two output signals is delivered to a respective power amplifier for driving a 2-way speaker system.

A combination of two or more EC-100's makes it possible to drive a 3-way or 4-way speaker system.

The transfer function G<sub>H</sub>(s) of a high pass filter is given by the formula:

The transfer function G<sub>p</sub>(s) of a phase shifter is expressed

$$G_{P}(s) = -\frac{S - \omega_{0}}{S + \omega_{0}} \qquad 2$$

Further, the added output (Eq. 1 + Eq. 2) of the adder is:

$$G_{H}(s) + G_{P}(s) = \frac{\omega_{0}^{2}}{(S + \omega_{0})^{2}} \dots 3$$

The transfer function of Eq. 3 accords with that of a low pass filter circuit. Therefore the output of the adder is a signal of lower frequency range.

The crossover frequency setting of EC-100 at 19 steps from 66 Hz to 7.4 kHz is possible by adjusting the Frequency Control VR001.

The Frequency Control is interlocked at 19 frequency positions in total, including 10 positions marked on the Frequency Control and 9 positions at the middle of them. These frequencies are 66, 68, 78, 95, 120, 170, 250, 320, 370, 440, 530, 660, and 880 Hz and 1.4 k, 2.4 k, 3.9 k, 5.4 k, 7 k, and 7.4 kHz. The attenuation characteristic of the filters is 12 dB/oct.

EC-100 has the same characteristics as conventional multiband filter circuits; however, in the crossover frequency switching system of EC-100 is improved from conventional systems that have to change the resistance and capacitance simultaneously to the system changing only the resistance.

#### **Specifications**

Maximum Power Consumption . . . 2 VA Current Consumption . . . . . . . 100 mA Attenuation . . . . . . . . . . . . . . . 12 dB/oct.

Crossover Frequencies . . . . . . . . . . . 66, 68, 78, 95, 120, 170, 250, 320, 370, 440, 530,

660, 880 Hz, 1.4 k, 2.4 k, 3.9 k, 5.4 k, 7 k, 7.4 kHz Distortion . . . . . . . . . . . less than 0.005% (20 Hz -

20 kHz) Signal-to-Noise Ratio . . . . . . . better than 110 dB (IHF-A

Network)

Ref. Input Level/Input Impedance . 1 V/50  $k\Omega$ 

Ref. Output Level/Output

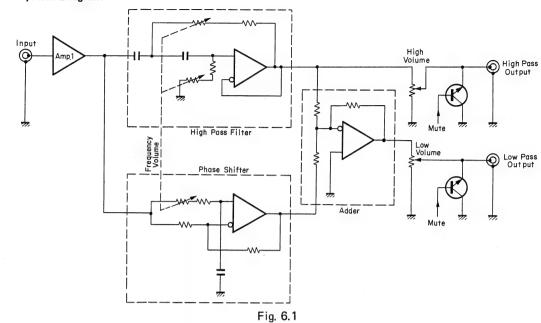
Impedance . . . . . . . . . . . . . 1 V/560  $\Omega$  Maximum Input Level . . . . . . . 4 V Mute Function . . . . . . . . Furnished

Dimensions . . . . . . . . . . . . . . . . . 7-1/2(W) x 2-3/8(H) x 3-15/16(D) inches

190(W) x 60(H) x 100(D) mm

Weight . . . . . . . . . . . . . . . 2.4 lb, 1.1 kg

#### System Diagram



#### **Schematic Diagram**

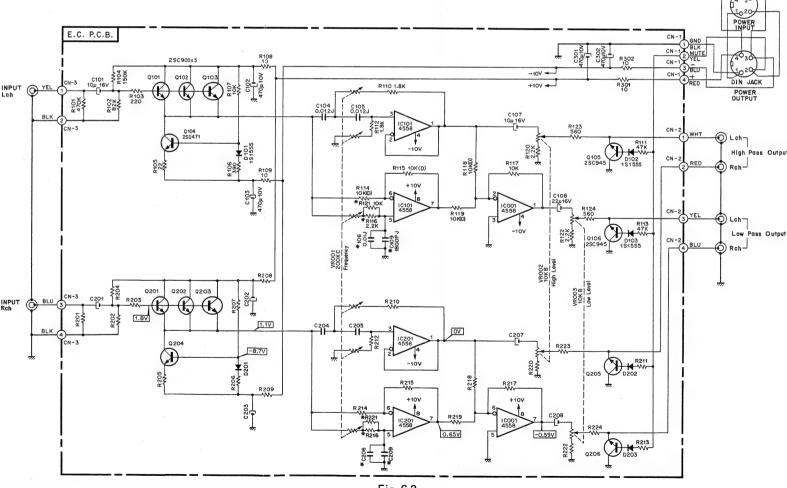


Fig. 6.2

#### Note:

Resistors and capacitors marked with \* will be adjusted in order to achieve accurate crossover frequencies when frequency volume is interlocked at 19

The standard value of these resistors and capacitors are shown in the figure.

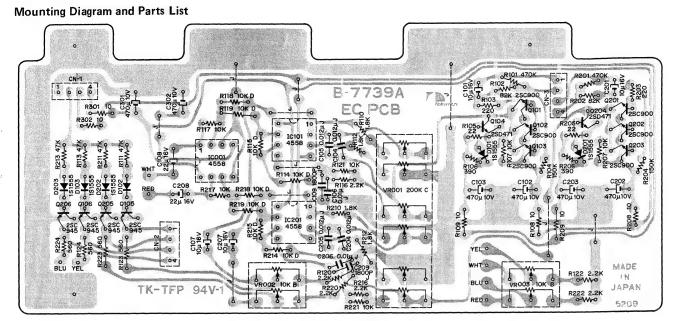


Fig. 6.3

Schematic Ref. No.	Part No.	Descript	ion	Schematic Ref. No.	Part No.	Description
	BA03868A	EC-100 P.C.B. Ass	'y	R114,115	0B05955A	Metal Film Resistor 10K ER0-25VK
				118,119		D
	0B07739B	EC P.C.B.		214,215		
IC001,101	0B06124A	IC	4558	218,219		
201				R116,120	0B05566A	Carbon Resistor 2.2K ERD-25V
Q101,102	0B01910A	Transistor	2SC900 (E)	122,216		
103,201				220,222		
202,203				R123,124	0B05678A	Carbon Resistor 560 ERD-25V
Q104,204	0B06066A	Transistor	2SD471	223,224		
Q105,106	0B01872A	Transistor	2SC945	C101,107	0B01412A	Electrolytic Capacitor
205,206				201,207		10μ 16V
D101,102	0B01909A	Silicon Diode	1S1555	C102,103	0B05884A	Electrolytic Capacitor
103,201			•	202,203		470μ 10V
202,203				301,302		
VR001	0B07182A	Volume	200K (C)	C104,105	0B05843A	Mylar Capacitor 0.012μ J
VR002,003	0B07181A	Volume	10K (B)	204,205		
R101,201	0B05700A	Carbon Resistor	470K ERD-25V J	C106,206	0B05681A	Mylar Capacitor 0.01μ J
R102,202	0B01564A	Carbon Resistor	82K ERD-25V J	C108,208	0B01862A	Electrolytic Capacitor
R103,203	0B05608A	Carbon Resistor	220 ERD-25V J			22μ 16V
R104,204	0B05593A	Carbon Resistor	150K ERD-25V J	C109,209	0B01913A	Mylar Capacitor 1800P J
R105,205	0B05606A	Carbon Resistor	22 ERD-25V J	CN1,2,3	0B08236A	4P-T Post
R106,206	0B05688A	Carbon Resistor	390 ERD-25V J			
R107,117	0B01833A	Carbon Resistor	10K ERD-25V J		į.	
121,207						
217,221				l		
R108,109	0B05663A	Carbon Resistor	10 ERD-25V J	1		
208,209				l		
301,302						
R110,112	0B01830A	Carbon Resistor	1.8K ERD-25V J	1		
210,212						
R111,113	0B05641A	Carbon Resistor	47K ERD-25V J			
211,213				l		
-						



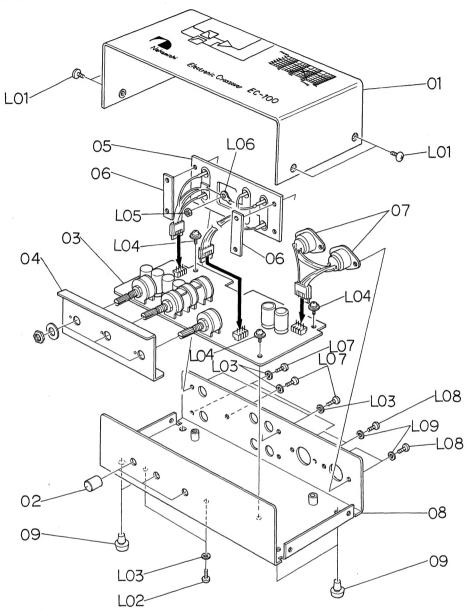


Fig. 6.4

Schematic Ref. No.	Part No.	Description	Q'ty	Schematic Ref. No.	Part No.	Description	Q'ty
		EC-100 Mechanism		L02	0E00593A	Screw M3x6 Philips Binding Head	2
01	0H03528A	Upper Cover EC	1	L03	0E00157A	Washer 3 mm (plastics)	7
02	HA03714A	VR Knob Ass'y	3	L04	0E00606A	Screw M3x6 Philips Pan Head	3
03	BA03868A	EC-100 P.C.B. Ass'y	1			(3A)	
04	0J03689B	VR Holder MX	1	L05	0E00507A	Nut Hex. M3	1
05	0B08290B	6P Pin Jack	1	L06	0E00037A	Earth Lug B-5	1
06	0J03277A	Metal Seat Nut	2	L07	0E00594A	Screw M3x8 Philips Binding	5
07	0B08355A	4P DIN Socket	2			Head	
80	HA03713A	Main Chassis EC Ass'y	1	L08	0E00714A	Screw M2.6x6 Philips Binding	4
09	0H03437A	Rubber Foot	4			Head	
L01	0E00713A	Screw M3x6 Philips Truss Head	4	L09	0E00651A	Washer 2.6 mm (plastics)	4

#### 7. MX-100 MICROPHONE MIXER

#### General

MX-100 is a mixing unit having three microphone inputs for L-channel, R-channel, and Blend. In addition to the use as a simple microphone mixer connected to line input terminals on a tape deck, the unit allows the application to a PA (public address) amplifier directly connected to an Aux. input of a preamplifier, etc.

Further, connection of this unit to Nakamichi 600 (a cassette console) makes microphone recording by Nakamichi 600 possible.

In addition, connection to the line input of a cassette system, such as Nakamichi 700II, 1000II or 500, allows recording using six microphones.

In Fig.7.1, the gain of the L-channel microphone amplifier is given by the formula:

$$Av(L) = \frac{Ry_1}{R_1 + Rx_1 + Ry_1} \dots 1$$

and the gain of blend microphone amplifier:

The gains of the mixing amplifier:

 $Av(ML) = R_5/R_3$  (for L-channel mic. amp. output),  $Av(MB) = R_5/R_4$  (for Blend mic. amp. output). Therefore the output of the L-channel is expressed as:

$$Av(LO) = Av(L) \frac{R_5}{R_3} + Av(B) \frac{R_5}{R_4}$$

Similar to the L-channel, the signal of blend microphone is mixed in the R-channel.

**Specifications** 

Maximum Power Consumption . . . 1 VA
Current Consumption . . . . . . 50 mA

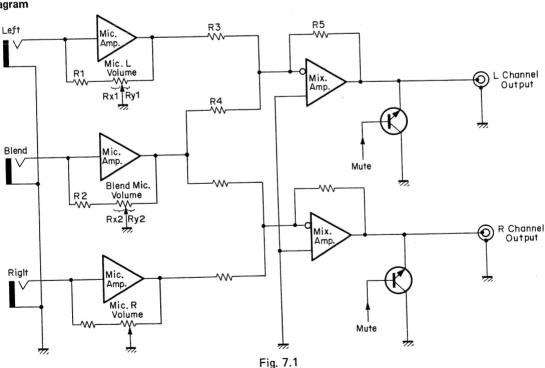
Total Harmonic Distortion . . . . 0.05% (10 kHz, 1 V Output,

Output Level/Output Impedance . . . 100 mV/560 12 Maximum Input Level . . . . . . . 1 V (+ 74 dB) Mute Function . . . . . . . . Furnished

190(W) × 60(H) × 110(D)mm

Weight . . . . . . . . . . . . . . 2.7 lb, 1.2 kg

### System Diagram





#### Schematic Diagram

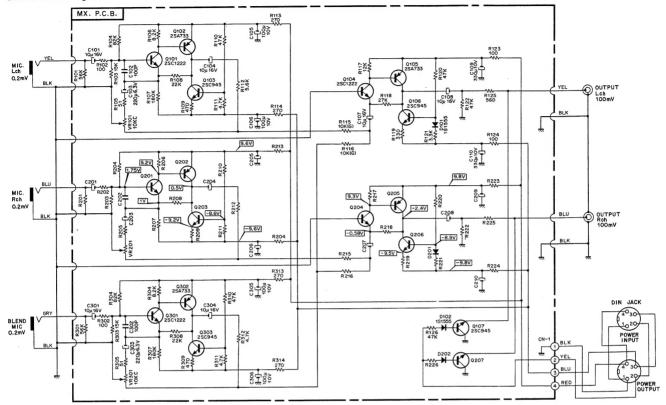


Fig. 7.2

304

305

306

307

308

R105,205

R106,206

R107,207

R108,208

0B05847A

0B01878A

0B05669A

0B05661A

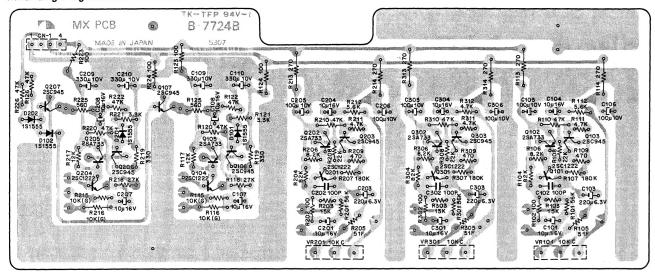


Fig. 7.3

Schematic Ref. No.	Part No.	Descripti	on	Schematic Ref. No.	Part No.	Descripti	on ·	
	BA03866A	MX-100 P.C.B. Ass	'y	R109,209 309	0B01792A	Carbon Resistor	470	ERD-14V J
	0B07724A	MX P.C.B.		R110,120	0B05562A	Carbon Resistor	47K	ERD-14V J
Q101,104	0B06062A	Transistor	2SC1222 (2)	122,126				
201,204				210,220				
301	)			222,226				
Q102,105	0B06013A	Transistor	2SA733	310				
202,205				R111,211	0B01795A	Carbon Resistor	4.7K	ERD-14V J
302				311,312				
Q103,106	0B01872A	Transistor	2SC945	R112,212	0B05673A	Carbon Resistor	5.6K	ERD-14V J
107,203	i			R113,114	0B05645A	Carbon Resistor	270	ERD-14T J
206,207				213,214				
303		·		313,314				
D101,102	0B01909A	Silicon Diode	1S1555	R115,116	0B05895A	Metal Film Resistor	10K	ER0-25VK
201,202				215,216				G
VR101,201	0B07175A	Volume	10K (C)	R117,217	0B05650A	Carbon Resistor	12K	ERD-14V J
301				R118,218	0B05538A	Carbon Resistor	27K	ERD-14V J
R101,201	0B05563A	Carbon Resistor	56K ERD-14V J	R119,219	0B01789A	Carbon Resistor	330	ERD-14V J
301			•	R121,221	0B01793A	Carbon Resistor	3.3K	ERD-14V J
R102,123	0B05558A	Carbon Resistor	100 ERD-14V J	R125,225	0B05678A	Carbon Resistor	560	ERD-14V J
124,202				C101,104	0B01412A	Electrolytic Capacit	or	•
223,224				107,108			10μ	16V
302				201,204				
R103,203	0B05591A	Carbon Resistor	15K ERD-14V J	207,208				
303				301,304				
R104,204	0B01564A	Carbon Resistor	82K ERD-14V J	C102,202	0B01288A	Ceramic Capacitor	100P	

#### Mechanism Ass'y and Parts List

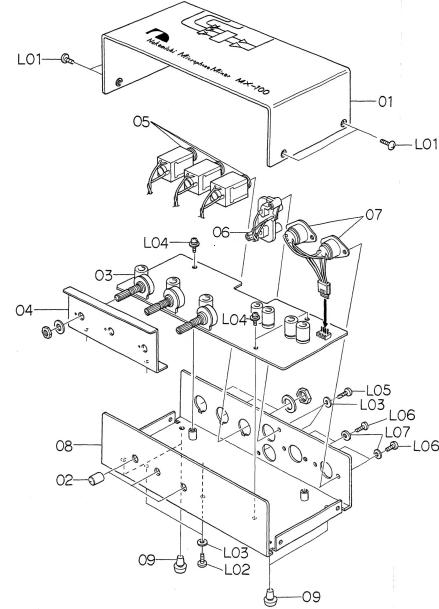


Fig. 7.4

						4	
Schematic Ref. No.	Part No.	Description	Q'ty	Schematic Ref. No.	Part No.	Description	Q'ty
		MX-100 Mechanism		L02	0E00593A	Screw M3x6 Philips Binding Head	2
01	0H03526A	Upper Cover MX	1	L03	0E00157A	Washer 3 mm (plastics)	4
. 02	HA03714A	VR Knob Ass'y	3	L04	0E00606A	Screw M3x6 Philips Pan Head	3
03	BA03866A	MX-100 P.C.B. Ass'y	1			(3A)	
04	0J03689B	VR Holder MX	1	L05	0E00766A	Screw M3x8 Philips Binding	2
05	0B03882A	Headphone Jack	3			Head TP	
06	0B08362A	2P Pin Jack	1	L06	0E00714A	Screw M2.6x6 Philips Binding	4
07	0B08355A	4P DIN Socket	2			Head	
80	HA03711A	Main Chassis MX Ass'y	1	L07	0E00651A	Washer 2.6 mm (plastics)	4
09	0H03437A	Rubber Foot	4				
L01	0E00713A	Screw M3x6 Philips Truss	4				
	j .	Lload	1				l .

302

303

C103,203

C105,106

205,206

305,306 C109,110

209,210

CN1

0B01394A

0B05885A

0B05841A

0B08236A

Electrolytic Capacitor

**Electrolytic Capacitor** 

4P-T Post

100μ 10V

330µ 10V

Metal Film Resistor 51 ER0-25VK

Carbon Resistor

Carbon Resistor

Carbon Resistor

8.2K ERD-14V J

180K ERD-14V J

22K ERD-14V J